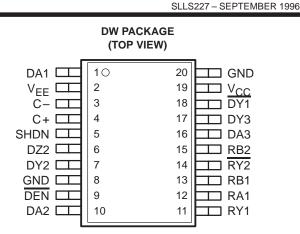
- Single-Chip Interface Solution for the 9-Pin GeoPort[™] Peripheral Data Circuit-Terminating Equipment (DCE) for the Intelligent Network Port
- Designed to Operate up to 4-Mbits/s Full Duplex
- Single 5-V Supply Operation
- 10-kV ESD Protection on Bus Terminals
- Backward Compatible with AppleTalk[™] and LocalTalk[™] LANs
- Combines Multiple Components into a Single Chip Solution
- Complements the SN75LBC776 9-Terminal GeoPort Host Data Terminal Equipment (DTE) Interface Device
- LinBiCMOS[™] Process Technology

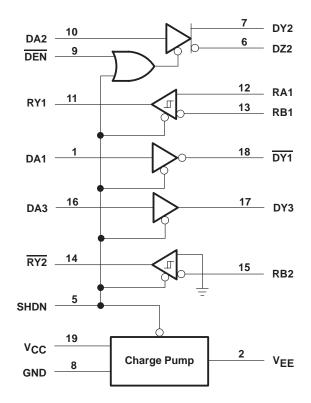
description

The SN75LBC777 is a low-power LinBiCMOS device that incorporate the drivers and receivers for a 9-pin GeoPort peripheral interface. GeoPort combines hybrid EIA/TIA-422-B and EIA/ TIA-423-B drivers and receivers to transmit data up to four-Mbit/s full duplex. GeoPort is a serial communications standard that is intended to replace the RS-232, AppleTalk, and printer ports all in one connector in addition to providing real-time data transfer capability. The SN75LBC777 provides point-to-point connections between GeoPort-compatible devices with data transmission rates up to 4-Mbit/s full duplex over a 4-foot cable. Applications include connection to telephone, integrated services digital network (ISDN), digital sound and imaging, fax-data modems, and other traditional serial and parallel connections. The GeoPort is backwardly compatible to both LocalTalk and AppleTalk LANs.

While the SN75LBC777 is powered off ($V_{CC} = 0$) the outputs are in a high-impedance state. When the shutdown (SHDN) terminal is high, the charge pump is powered down and the outputs are in a high-impedance state. When high, the driver enable (\overline{DEN}) terminal puts the outputs of the differential driver into a high-impedance state.



logic diagram (positive logic)





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description (continued)

A switched-capacitor voltage converter generates the negative voltage required from a single 5-V supply using two 0.33- μ F capacitors. One capacitor is between the C+ and C- terminals and the other is between V_{EE} and ground.

The SN75LBC777 is characterized for operation over the 0°C to 70°C temperature range.

	INPUTS		ENA	BLE		OUTF	PUTS	
DA1	DA2	DA3	SHDN	DEN	DY1	DY2	DZ2	DY3
Н	Х	Н	L	Х	L	Х	Х	Н
L	Х	L	L	Х	н	Х	Х	L
Х	н	Х	L	L	Х	н	L	Х
Х	L	Х	L	L	L X		н	Х
OPEN	OPEN	OPEN	L	L	L	н	L	н
Х	Х	Х	н	Х	Z	Z	Z	Z
х	Х	Х	х	Н	Х	Z	Z	Х
Х	Х	Х	OPEN	OPEN	Z	Z	Z	Z

DRIVER FUNCTION TABLE

H = high level, L= low level, X = irrelevant, ? = indeterminate, Z = high impedance (off)

				_	
	INPUT	S	ENABLE	OUT	PUTS
RA1	RB1	RB2	SHDN	RY1	RY2
н	L	Н	L	Н	L
L	Н	L	L	L	Н
OF	PEN	OPEN	L	н	Н
SHC	DRT [†]	SHORT [†]	L	?	?
X	Х	Х	н	Z	Z
Х	Х	Х	OPEN	Z	Z

RECEIVER FUNCTION TABLE

 $^{+}$ -0.2 V < V_{ID} < 0.2 V H = high level, L= low level, X = irrelevant, ? = indeterminate, Z = high impedance (off)



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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Positive supply voltage range, V _{CC,} (see Note 1) Negative supply voltage range, V _{EE,} (see Note 1) Receiver input voltage range (RA1, RB1, RB2) Receiver differential input voltage ran <u>ge, V_{ID}</u>	7 to 0.5 V 15 V to 15 V 12 V to 12 V
Receiver output voltage range (RY1, RY2)	
Driver output voltage range (Power Off)(<u>DY1</u> , DY2, DZ2, DY3) Driver output voltage range (Power On)(<u>DY1</u> , DY2, DZ2, DY3)	
Driver input voltage range (DA, SHDN, DEN)	$\ldots \ldots -0.5$ V to V _{CC} +0.4 V
Electrostatic discharge (see Note 2)	
Bus Pins (Class 3 A)	10 kV
Bus Pins (Class 3 B)	600 V
All Pins (Class 3, A)	2 kV
All Pins (Class 3 B)	200 V
Continuous total power dissipation	See Dissipation Rating Table
Operating free-air temperature range, T _A	$\dots \dots 0^{\circ}C$ to $70^{\circ}C$
Storage temperature range, T _{stg} Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	65°C to 150 °C 260°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. All voltages values are with respect to the network ground terminal unless otherwise noted.

2. This rating is measured using MIL-STD-883C Method, 3015.7.

DISSIPATION RATING TABLE

PACKAGE	$T_A \le 25^{\circ}C$ POWER RATING	DERATE FACTOR ABOVE T _A = 25°C	T _A = 70°C POWER RATING
DW	1125 mW	9.0°C	720 mW



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recommended operating conditions

	MIN	NOM	MAX	UNIT
Supply voltage, V _{CC}	4.75	5	5.25	V
High-level input voltage, VIH (DA, SHDN, DEN)	2		5.25	V
Low-level input voltage, VIL (DA, SHDN, DEN)			0.8	V
Receiver common-mode input voltage, VIC	-7		7	V
Receiver differential input voltage, VID	-12		12	V
Voltage converter filter capacitance	0.33			μF
Voltage converter filter capacitor equivalent series resistance (ESR)	0		0.2	Ω
Operating free-air temperature, T _A			70	°C

driver electrical characteristics over operating free-air temperature range (unless otherwise noted)

	PARAMETER		TEST CON	DITIONS	MIN	TYP	MAX	UNIT
Vau	High lovel output veltage		RL= 12 kΩ		3.6	4.5		V
VOH	High-level output voltage	Single ended,	R _L = 120 Ω		2	3.6		V
Max		See Figure 1	R _L = 12 kΩ			-4.5	-3.6	V
VOL	Low-level output voltage		R _L = 120 Ω			-2.7	-1.8	V
IVOD	Magnitude of differential outpu VDY – VDZ	it voltage	R _L = 120 Ω,	See Figure 2	4			V
$\Delta V_{OD} $	Change in differential voltage	magnitude	1			250	mV	
Voc	Common-mode output voltage	9			-1		3	V
∆VOC(SS)	Magnitude of change, commo state output voltage	Magnitude of change, common-mode steady- state output voltage		See Figure 3			200	mV
∆VOC(PP)	Magnitude of change, commo peak-to-peak output voltage	n-mode			700		mV	
1	Cumple cumpat		$SHDN = \overline{DEN} = 0 V,$	No Load		7	15	mA
lcc	Supply current		SHDN = $\overline{\text{DEN}}$ = 5 V,	No Load			100	μΑ
IOZ	High-impedance output currer	nt	V _{CC} = 0 or 5 V,	$-10 \le V_O \le 10 \text{ V}$			±100	μΑ
los	Short-circuit output current		V _{CC} = 5.25 V, See Note 3	$-5 \text{ V} \le \text{V}_{O} \le 5 \text{ V},$		±170	±450	mA

NOTE 3: Not more than one output should be shorted at one time.



	PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
^t PHL	Propagation delay time, high-to-low level output				40	75	ns
^t PLH	Propagation delay time, low-to-high level output				40	75	ns
^t PZL	Driver output enable time to low-level output	SHDN			25	100	μs
^t PZH	Driver output enable time to high-level output	SHDN	Single-ended,		25	100	μs
^t PLZ	Driver output disable time from low-level output	SHDN	$R_L = 120 \Omega$, See Figure 4		30	100	ns
^t PHZ	Driver output disable time from high-level output	SHDN	g		30	100	ns
t _r	Rise time			10	25	75	ns
t _f	Fall time			10	25	75	ns
^t PHL	Propagation delay time, high-to-low level output				40	75	ns
^t PLH	Propagation delay time, low-to-high level output				40	75	ns
·	Driver output enable time to low-level output	SHDN	7		25	100	μs
^t PZL	Driver output enable time to low-level output	DEN	1 1		35	100	ns
4	Driver extent enable time to high level extent	SHDN			25	100	μs
^t PZH	Driver output enable time to high-level output	DEN	Differential,		35	150	ns
4		SHDN	$R_L = 120 \Omega$, See Figure 5		30	100	ns
^t PLZ	Driver output disable time from low-level output	DEN			30	100	ns
	Driver entend dischle first form high land autout	SHDN	7 1		35	100	ns
^t PHZ	Driver output disable time from high-level output	DEN	7 1		35	100	ns
t _r	Rise time	-	7	10	25	75	ns
t _f	Fall time		7 1	10	25	75	ns
^t SK(P)	Pulse skew, tpLH - tpHL					22	ns

driver switching characteristics over recommended operating conditions (unless otherwise noted)

receiver electrical characteristics over free-air temperature range (unless otherwise noted)

	PARAMETER	TEST CO	NDITIONS	MIN	TYP	MAX	UNIT
VIT+	Positive-going input threshold voltage					200	mV
VIT-	Negative-going input threshold voltage]		-200			mV
V _{hys}	Differential input voltage hysteresis ($V_{IT+} - V_{IT-}$)				50		mV
∨он	High-level output voltage (see Note 4)	I _{OH} = 2 mA,	$V_{IC} = 0$	2	4.9		V
VOL	Low-level output voltage	$I_{OL} = -2 \text{ mA},$	$V_{IC} = 0$		0.2	0.8	V
	Chart circuit output outport	$\Lambda^{O} = 0$		-85	-45		mA
los	Short-circuit output current	V _O = 5.25 V			45	85	mA
RI	Input resistance	$V_{CC} = 0 \text{ or } 5.25 \text{ V},$	$-12 \text{ V} \le \text{V}_I \le 12 \text{ V}$	6	30		kΩ

NOTE 4: If the inputs are left unconnected, RA1 interprets this as a high-level input and RB1 and RB2 interpret this as a low-level input so that all outputs are at the high level.



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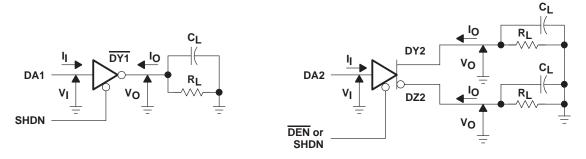
receiver switching characteristics over free-air temperature range (unless otherwise noted)

	PARAMETER	TEST CO	NDITIONS	MIN	TYP	MAX	UNIT
^t PHL	Propagation delay time, high-to-low level output				30	75	ns
^t PLH	Propagation delay time, low-to-high level output				30	75	ns
t _r	Rise time	$R_L = 2 k\Omega,$ See Figure 6			15	30	ns
t _f	Fall time				15	30	ns
t _{sk(p)}	Pulse skew t _{PLH-} t _{PHL}					20	ns
^t PZL	Receiver output enable time to low-level output				35	100	ns
^t PZH	Receiver output enable time to high-level output	Differential,	C _L = 50 pF,		35	100	ns
^t PLZ	Receiver output disable time from low-level output	See Figure 7			21	100	ns
^t PHZ	Receiver output disable time from high-level output				21	100	ns
tpzl	Receiver output enable time to low-level output				12	25	μs
^t PZH	Receiver output enable time to high-level output	Single-ended,	C _I = 50 pF,		12	25	μs
t _{PLZ}	Receiver output disable time from low-level output	See Figure 7			25	100	ns
^t PHZ	Receiver output disable time from high-level output				125	400	ns



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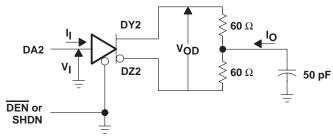
PARAMETER MEASUREMENT INFORMATION



TEST CIRCUIT

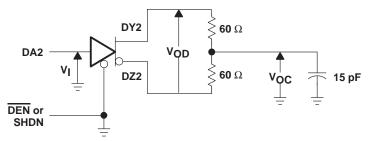
NOTES: A. C_L = 50 pF B. Driver 3 is a noninverting version of driver 1.





TEST CIRCUIT





TEST CIRCUIT (see Note A)

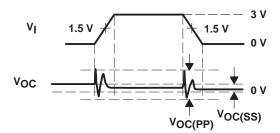


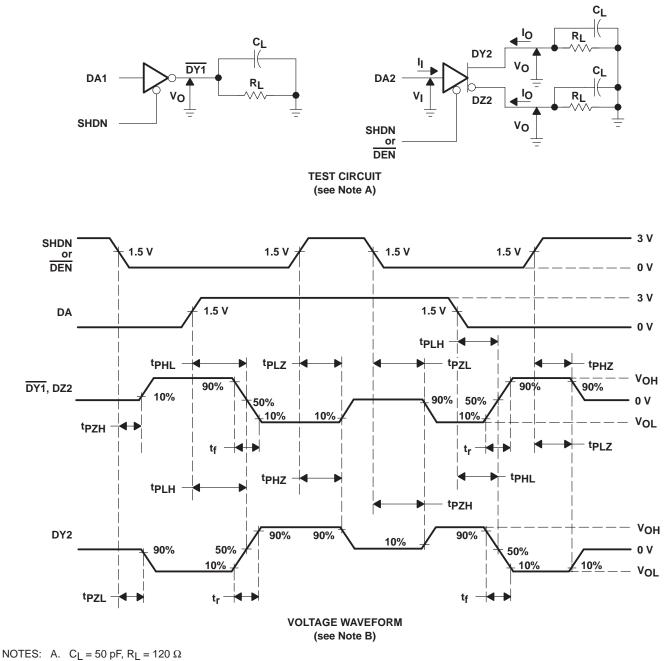


Figure 3. Differential Driver Common-Mode Output Voltage Test Circuit and Waveform



SN75LBC777 SINGLE CHIP GEOPORT[™]/AppleTalk[™] TRANSCEIVER

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PARAMETER MEASUREMENT INFORMATION

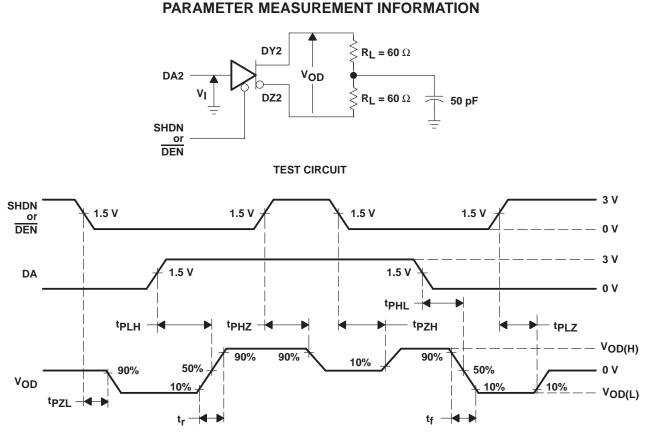
B. The input waveform t_r , $t_f \le 10$ ns.

C. Driver 3 is a noninverting version of driver 1.

Figure 4. Single-Ended Driver Propagation and Transition Times Test Circuits and Waveform



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VOLTAGE WAVEFORM

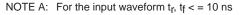
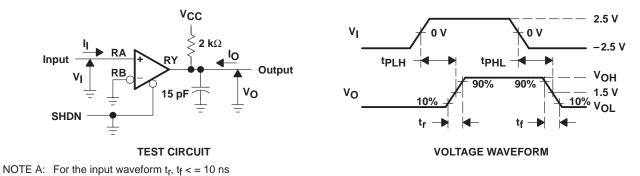
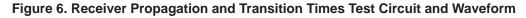


Figure 5. Differential Driver Propagation and Transition Times Test Circuit and Waveforms

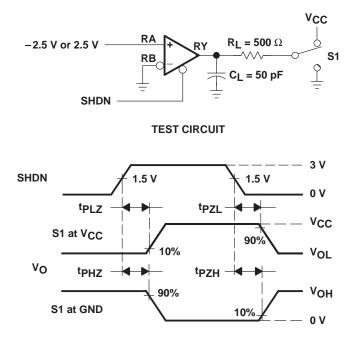






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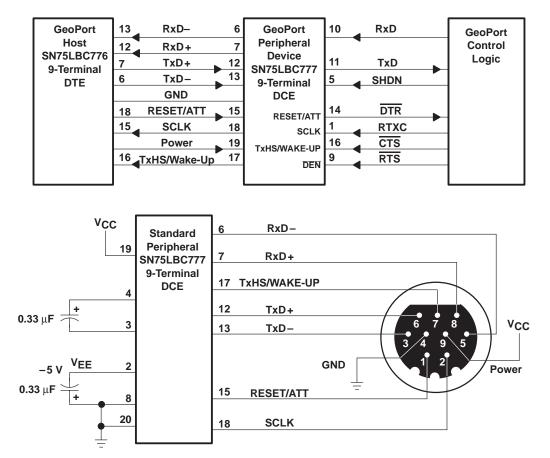
PARAMETER MEASUREMENT INFORMATION

VOLTAGE WAVEFORM

NOTE A: For the input waveform t_r , $t_f < = 10$ ns

Figure 7. Receiver Enable and Disable Test Circuit and Waveforms





APPLICATION INFORMATION

NOTE A: A potential charge pump capacitor is the AVX 0805YC334MATXA or an equivalent.

Figure 8. GeoPort 9-terminal DCE Connection Application



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generator characteristics

		TEOT	CONDITIONS	232/	V.28	423/	V.10	562		UNIT
	PARAMETER	TEST	CONDITIONS	MIN MAX		MIN MAX MIN M		MAX		
		Open circuit			25	4	6		13.2	V
VO	Output voltage magnitude	$3 \text{ k}\Omega \leq \text{R}_L \leq 1$	$3 \text{ k}\Omega \leq \text{R}_{\text{L}} \leq 7 \text{ k}\Omega$		15	N	A	3.7		V
		RL = 450 Ω		N	A	3.6		N	A	V
IOS	Short-circuit output current	$V_{O} = 0$			100		150		60	mA
R _{O(OFF)}	Power-off source resistance	$V_{CC} = 0,$	V _O < 2 V	300		N	A	300		Ω
lO(OFF)	Power-off output current	$V_{CC} = 0,$	V _O < 6 V	N	A		±100	N	A	μA
SR	Output voltage slew rate				30	N	A	4	30	V/μs
		±3.3 V to ±3.	3 V	N	A	N	A	0.22	2.1	μs
tt	Output transition time	±3 V to ±3 V			0.04	N	A	N	Ą	ui†
		10% to 90%		N	A		0.3	N/	Ą	ui†
VO(RING)	Output voltage ringing			N	A		10%		5%	

 $\ensuremath{^{+}}\xspace$ ui is the unit interval and is the inverse of the signaling rate (a.k.a. bit time).

receiver characteristics

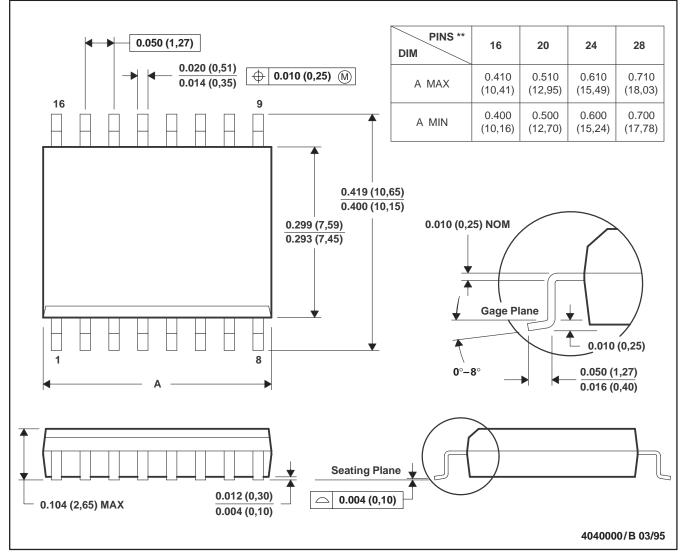
	PARAMETER	TEST CONDITIONS	232/\	/. 28	423/	/.10	56	2	UNIT
	FARAMETER	TEST CONDITIONS	MIN MAX		MIN	MAX	MIN	MAX	UNIT
V	Input voltage			25		10		25	V
V	Input voltage threshold	V < 15 V	-3	3	N	Ą	-3	3	V
VIT	input voltage trireshold	VI < 10 V	N/	A	-0.2	0.2	N/	4	V
в.		3 V < V _I < 15 V	3	7	N	Ą	3	7	kΩ
RI	Input resistance	V _I < 10 V	N/	٩	4		N/	4	kΩ



MECHANICAL INFORMATION

PLASTIC SMALL-OUTLINE PACKAGE

DW (R-PDSO-G**) 16 PIN SHOWN



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).

D. Falls within JEDEC MS-013





PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
SN75LBC777DW	ACTIVE	SOIC	DW	20	25	Pb-Free (RoHS)	CU NIPDAU	Level-2-250C-1YEAR/ Level-1-220C-UNLIM
SN75LBC777DWR	ACTIVE	SOIC	DW	20	2000	Pb-Free (RoHS)	CU NIPDAU	Level-2-250C-1YEAR/ Level-1-220C-UNLIM

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - May not be currently available - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

None: Not yet available Lead (Pb-Free).

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⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDECindustry standard classifications, and peak solder temperature.

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DW (R-PDSO-G20)

PLASTIC SMALL-OUTLINE PACKAGE



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B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).

D. Falls within JEDEC MS-013 variation AC.



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